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Vishay Siliconix

Automotive N-Channel 30 V (D-S) 175 °C MOSFET

PowerPAK® 1212-8W Single

Bottom View

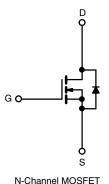
Marking code: Q034

PRODUCT SUMMARY			
V _{DS} (V)	30		
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.0085		
$R_{DS(on)}(\Omega)$ at $V_{GS} = 4.5 \text{ V}$	0.0100		
I _D (A)	16		
Configuration	Single		
Package	PowerPAK 1212-8W		

FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified d
- 100 % Rq and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)								
PARAMETER		SYMBOL	LIMIT	UNIT				
Drain-source voltage		V_{DS}	30	V				
Gate-source voltage		V_{GS}	± 20	V				
Continuous drain current a	T _C = 25 °C	L_	16					

PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V_{DS}	30	٧
Gate-source voltage	V_{GS}		± 20	V
Continuous drain current ^a	T _C = 25 °C	1	16	
Continuous drain current 4	T _C = 125 °C	I _D	16	
Continuous source current (diode conduction) a	Continuous source current (diode conduction) ^a			А
Pulsed drain current ^b		I _{DM}	64	
Single pulse avalanche current	L = 0.1 mH	I _{AS}	31	
Single pulse avalanche energy	L = 0.1 IIII1	E _{AS}	48	mJ
Maximum power dissipation ^b	T _C = 25 °C	D	62	W
iviaximum power dissipation -	T _C = 125 °C	P_{D}	20	T vv
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C
Soldering recommendations (peak temperature) e,	f		260	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-ambient	PCB mount c	R_{thJA}	81	°C/W	
Junction-to-case (drain)		R_{thJC}	2.4	C/VV	

Notes

- a. Package limited
- b. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- c. When mounted on 1" square PCB (FR4 material)
- d. Parametric verification ongoing
- e. See solder profile (www.vishay.com/doc?73257). The PowerPAK 1212-8W is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- f. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components



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PARAMETER	SYMBOL	TES	T CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static							
Drain-source breakdown voltage	V _{DS}	V _{GS}	$V_{GS} = 0, I_D = 250 \mu A$		-	-	V
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	= V _{GS} , I _D = 250 μA	1.5	2.0	2.5	V
Gate-source leakage	I _{GSS}	V _{DS} =	0 V, V _{GS} = ± 20 V	-	-	± 100	nA
		$V_{GS} = 0 V$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$				
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 30 V, T _J = 125 °C	-	-	50	μΑ
		$V_{GS} = 0 V$	V _{DS} = 30 V, T _J = 175 °C	-	-	150	
On-state drain current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	20	-	-	Α
		V _{GS} = 10 V	I _D = 16.4 A	-	0.0070	0.0085	Ω
Drain actives on state registeres 3		V _{GS} = 10 V	I _D = 16.4 A, T _J = 125 °C	-	-	0.0135	
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 16.4 A, T _J = 175 °C	-	-	0.0160	
		V _{GS} = 4.5 V	I _D = 16.4 A	-	0.0080	0.0100	
Forward transconductance b	9fs	V _{DS} =	= 15 V, I _D = 16.4 A	-	70	-	S
Dynamic ^b	_						
Input capacitance	C _{iss}			-	1492	1865	pF
Output capacitance	Coss	$V_{GS} = 0 V$	$V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$	-	280	350	
Reverse transfer capacitance	C _{rss}			-	108	135	
Total gate charge ^c	Qg			-	26	39	
Gate-source charge ^c	Q _{gs}	$V_{GS} = 10 \text{ V}$	$V_{DS} = 15 \text{ V}, I_D = 10 \text{ A}$	-	4.7	-	nC
Gate-drain charge ^c	Q _{gd}			-	4.3	-	
Gate resistance	R _g		f = 1 MHz		10	20	Ω
Turn-on delay time ^c	t _{d(on)}			-	7	11	
Rise time ^c	t _r	$V_{DD} = 15 \text{ V, } R_L = 3 \Omega$ $I_D \cong 5 \text{ A, } V_{GEN} = 10 \text{ V, } R_g = 1 \Omega$		-	21	32	ns
Turn-off delay time ^c	t _{d(off)}			-	49	74	
Fall Time ^c	t _f			-	18	27	
Source-Drain Diode Ratings and Char	acteristics ^b						
Pulsed current ^a	I _{SM}			-	-	64	Α
Forward voltage	V_{SD}	I _F = 15 A, V _{GS} = 0		_	0.82	1.2	V

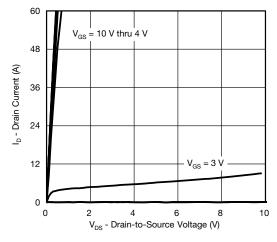
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

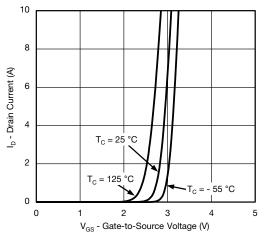
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



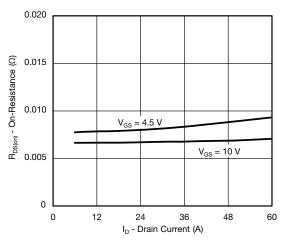
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



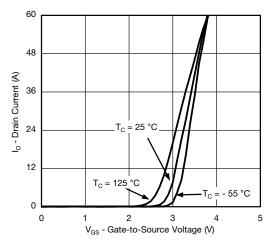
Output Characteristics



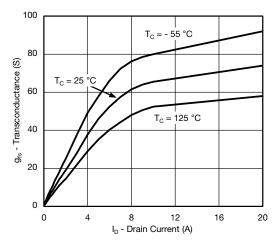
Transfer Characteristics



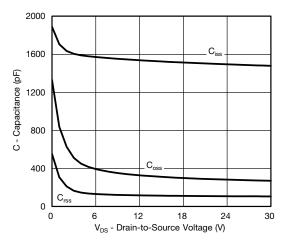
On-Resistance vs. Drain Current



Transfer Characteristics



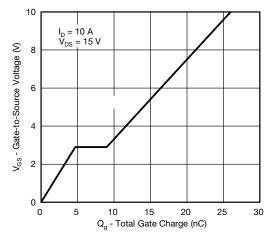
Transconductance



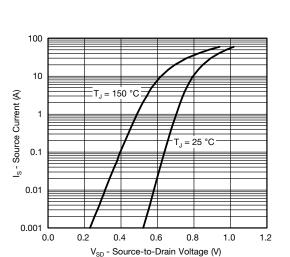
Capacitance



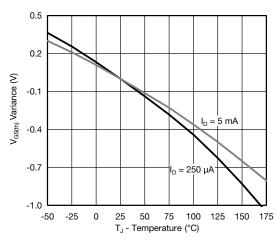
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



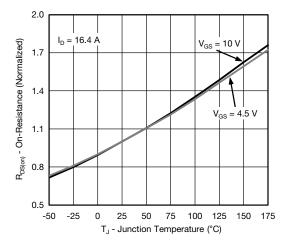
Gate Charge



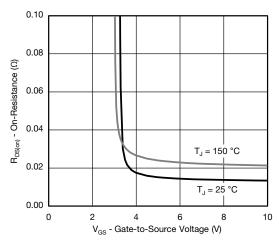
Source Drain Diode Forward Voltage



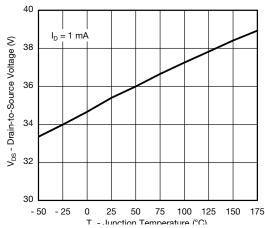
Threshold Voltage



On-Resistance vs. Junction Temperature



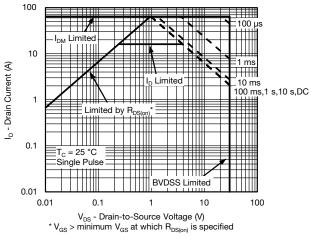
On-Resistance vs. Gate-to-Source Voltage



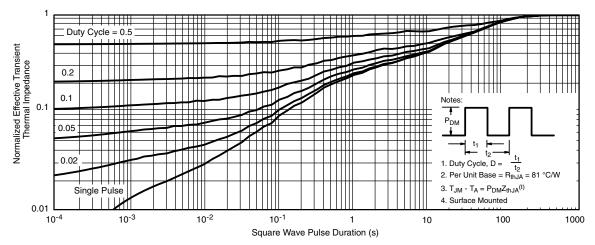
Drain Source Breakdown vs. Junction Temperature



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



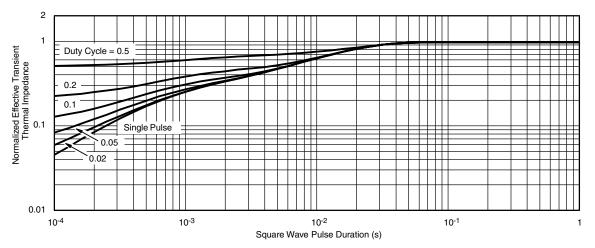
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient

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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

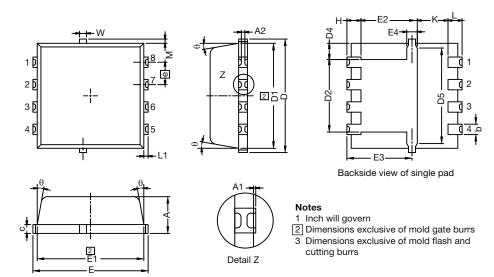
- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?75543.



PowerPAK® 1212-8W Case Outline



DIM.	MILLIMETERS			INCHES			
DIM.	MIN.	NOM.	NOM. MAX.		NOM.	MAX.	
Α	0.97	1.04	1.12	0.038	0.041	0.044	
A1	0	=	0.05	0	-	0.002	
A2	0	-	0.13	0	-	0.005	
b	0.23	0.30	0.41	0.009	0.012	0.016	
С	0.23	0.28	0.33	0.009	0.011	0.013	
D	3.20	3.30	3.40	0.126	0.130	0.134	
D1	2.95	3.05	3.15	0.116	0.120	0.124	
D2	1.98	2.11	2.24	0.078	0.083	0.088	
D4		0.47 typ.			0.0185 typ.		
D5		2.3 typ.		0.090 typ.			
Е	3.20	3.30	3.40	0.126	0.130	0.134	
E1	2.95	3.05	3.15	0.116	0.120	0.124	
E2	1.47	1.60	1.73	0.058	0.063	0.068	
E3	1.75	1.85	1.98	0.069	0.073	0.078	
E4		0.34 typ.		0.013 typ.			
е		0.65 BSC.		0.026 BSC			
K		0.86 typ.		0.034 typ.			
Н	0.30	0.41	0.51	0.012	0.016	0.020	
L	0.30	0.43	0.56	0.012	0.017	0.022	
L1	0.06	0.13	0.20	0.002	0.005	0.008	
θ	0°	-	12°	0°	-	12°	
W	0.15	0.25	0.36	0.006	0.010	0.014	
М		0.125 typ.		0.005 typ.			

DWG: 6032



RECOMMENDED MINIMUM PADS FOR PowerPAK® 1212-8 Single



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



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